

SGM48751

8:1 CMOS Analog Signal Multiplexer

GENERAL DESCRIPTION

The SGM48751 is a CMOS analog IC configured as an 8-channel multiplexer. This CMOS device can operate from 2.5V to 5.5V single supplies. Each switch can handle rail-to-rail analog signals. The off-leakage current is only 1nA (TYP) at +25°C.

All digital inputs can support 1.8V logic control I/O.

The SGM48751 is available in Green SOIC-16, SSOP-16, TSSOP-16 and TQFN-3×3-16L packages. It operates over an ambient temperature range of -40°C to +85°C.

APPLICATIONS

Battery-Operated Equipment
Audio and Video Signal Routing
Low-Voltage Data-Acquisition Systems
Communications Circuits
Automotive

FEATURES

- **Guaranteed On-Resistance
48Ω (TYP) with 5V Supply**
- **Guaranteed On-Resistance Match Between
Channels**
- **Low Off-Leakage Current 1nA (TYP) at +25°C**
- **Low On-Leakage Current 1nA (TYP) at +25°C**
- **Optimized Rise Time and Fall Time of A, B, C
Control Pins to Reduce Clock Feedthrough Effect**
- **2.5V to 5.5V Single Supply Operation**
- **1.8V Logic Compatible**
- **High Off-Isolation: -83dB ($R_L = 50\Omega$, $f = 1\text{MHz}$)**
- **-40°C to +85°C Operating Temperature Range**
- **Available in Green SOIC-16, SSOP-16, TSSOP-16
and TQFN-3×3-16L Packages**

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM48751	SOIC-16	-40°C to +85°C	SGM48751YS16G/TR	SGM48751YS16 XXXXX	Tape and Reel, 2500
	SSOP-16	-40°C to +85°C	SGM48751YQS16G/TR	SGM48751 YQS16 XXXXX	Tape and Reel, 3000
	TSSOP-16	-40°C to +85°C	SGM48751YTS16G/TR	SGM48751 YTS16 XXXXX	Tape and Reel, 4000
	TQFN-3×3-16L	-40°C to +85°C	SGM48751YTQ16G/TR	48751TQ XXXXX	Tape and Reel, 4000

MARKING INFORMATION

NOTE: XXXXX = Date Code and Vendor Code.

XXXXX

Vendor Code
Date Code - Week
Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

V_{CC} to GND -0.3V to 6V
 Voltage into Any Terminal ⁽¹⁾ -0.3V to ($V_{CC} + 0.3V$)
 Continuous Current into Any Terminal $\pm 20mA$
 Peak Current, $X_{_}$
 (Pulsed at 1ms, 10% duty cycle) $\pm 40mA$
 Junction Temperature $+150^{\circ}C$
 Storage Temperature Range $-65^{\circ}C$ to $+150^{\circ}C$
 Lead Temperature (Soldering, 10s) $+260^{\circ}C$
 ESD Susceptibility
 HBM 4000V

NOTE:

1. Voltages exceeding V_{CC} or GND on any signal terminal are clamped by internal diodes. Limit forward-diode current to maximum current rating.

RECOMMENDED OPERATING CONDITIONS

Supply Voltage Range 2.5V to 5.5V
 Operating Temperature Range $-40^{\circ}C$ to $+85^{\circ}C$

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

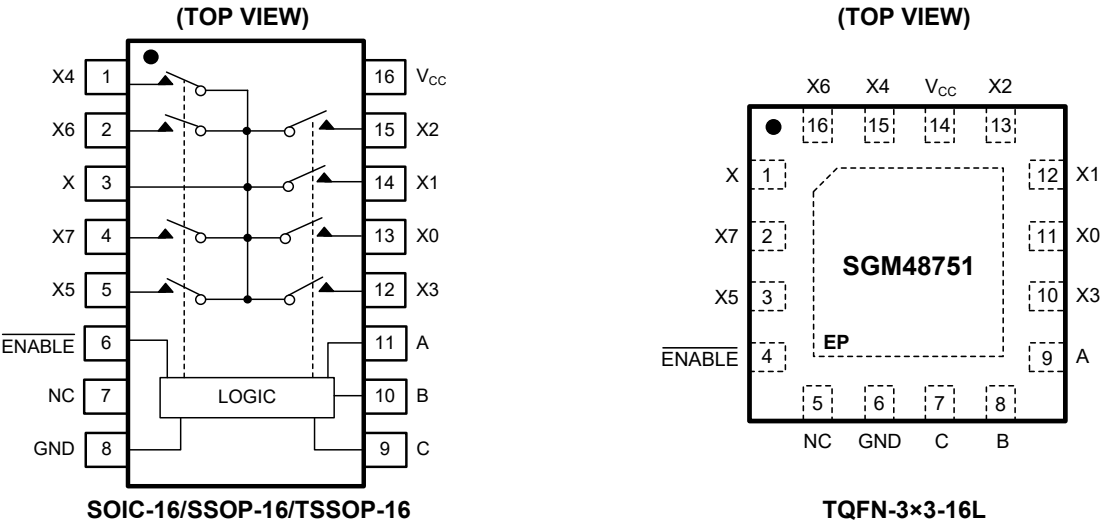
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATIONS



PIN DESCRIPTION

PIN		NAME	FUNCTION
SOIC-16/SSOP-16/TSSOP-16	TQFN-3x3-16L		
13, 14, 15, 12, 1, 5, 2, 4	11, 12, 13, 10, 15, 3, 16, 2	X0-X7	Analog Switch Inputs X0-X7.
3	1	X	Analog Switch “X” Output.
16	14	V _{CC}	Positive Analog and Digital Supply Voltage Input.
11	9	A	Digital Address “A” Input.
10	8	B	Digital Address “B” Input.
9	7	C	Digital Address “C” Input.
8	6	GND	Ground. Connect to digital ground.
7	5	NC	No Connect.
6	4	ENABLE	Digital Enable Input. Normally connected to GND.
—	Exposed Pad	EP	Exposed Pad. Connect EP to GND.

FUNCTION TABLE

ENABLE INPUT	SELECT INPUTS			ON SWITCHES
	C	B	A	
H	X	X	X	All Switches Open
L	L	L	L	X-X0
L	L	L	H	X-X1
L	L	H	L	X-X2
L	L	H	H	X-X3
L	H	L	L	X-X4
L	H	L	H	X-X5
L	H	H	L	X-X6
L	H	H	H	X-X7

X = Don't care.
NOTE: Input and output pins are identical and interchangeable. Either may be considered an input or output; signals pass equally well in either direction.

ELECTRICAL CHARACTERISTICS

(V_{CC} = 5.0V, Full = -40°C to +85°C, typical values are at T_A = +25°C, unless otherwise noted.)

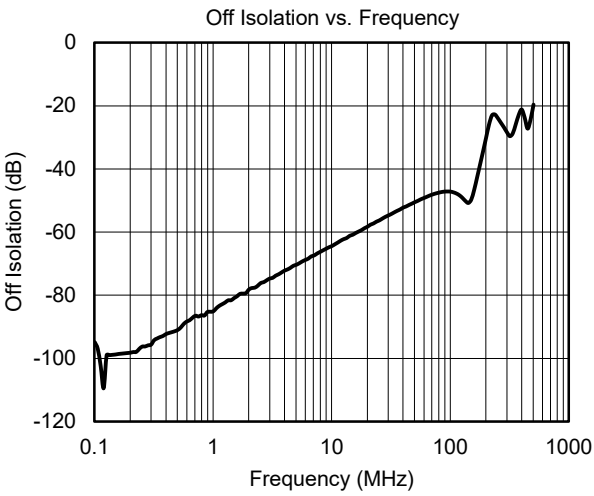
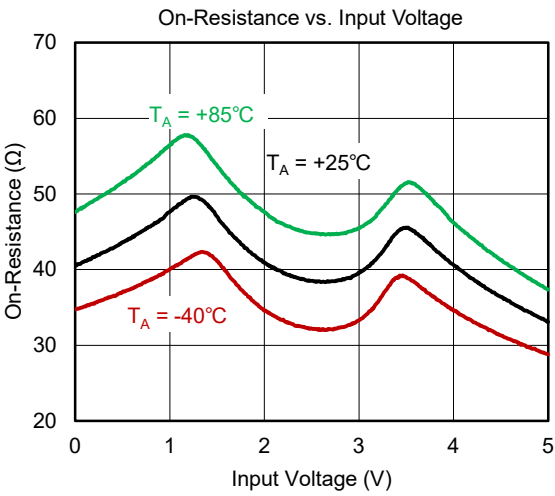
PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{X-} , V _X		Full	GND		V _{CC}	V
On-Resistance	R _{ON}	V _{CC} = 5.0V, I _X = 1mA	+25°C		48	58	Ω
			Full			67	
On-Resistance Match Between Channels	ΔR _{ON}	V _{CC} = 5.0V, I _X = 1mA	+25°C		1.5	5	Ω
			Full			5.3	
On-Resistance Flatness	R _{FLAT(ON)}	V _{CC} = 5.0V, I _X = 1mA	+25°C		17	25	Ω
			Full			28	
X ₋ Off Leakage Current	I _{X-(OFF)}	V _{CC} = 5.0V, V _{X-} = 4.5V or 0V, V _X = 4.5V or 0V	+25°C		1	1000	nA
X Off Leakage Current	I _{X(OFF)}	V _{CC} = 5.0V, V _{X-} = 4.5V or 0V, V _X = 4.5V or 0V	+25°C		1	1000	nA
X On Leakage Current	I _{X(ON)}	V _{CC} = 5.0V, V _X = 4.5V or 0V	+25°C		1	1000	nA
DIGITAL I/O							
Logic Input Logic Threshold High	V _{AH} , V _{BH} , V _{CH} , V _{ENABLE}		+25°C	1.7			V
Logic Input Logic Threshold Low	V _{AL} , V _{BL} , V _{CL} , V _{ENABLE}		+25°C			0.5	V
Input-Current High	I _{AH} , I _{BH} , I _{CH} , I _{ENABLE}	V _A , V _B , V _C , V _{ENABLE} = V _{CC}	+25°C		1	1000	nA
Input-Current Low	I _{AL} , I _{BL} , I _{CL} , I _{ENABLE}	V _A , V _B , V _C , V _{ENABLE} = 0V	+25°C		1	1000	nA
DYNAMIC CHARACTERISTICS							
Address Transition Time	t _{TRANS}	V _{X-} = ±3V, R _L = 300Ω, C _L = 35pF, Test Circuit 1	+25°C		85		ns
ENABLE Turn-On Time	t _{ON}	V _{X-} = 3V, R _L = 300Ω, C _L = 35pF, Test Circuit 2	+25°C		60		ns
ENABLE Turn-Off Time	t _{OFF}	V _{X-} = 3V, R _L = 300Ω, C _L = 35pF, Test Circuit 2	+25°C		70		ns
Internal A, B, C Rise Time	t _R		+25°C		45		ns
Internal A, B, C Fall Time	t _F		+25°C		50		ns
Break-Before-Make Time Delay	t _D	V _{X-} = 3V, R _L = 300Ω, C _L = 35pF, Test Circuit 3	+25°C		50		ns
Charge Injection	Q	R _S = 0Ω, C _L = 1nF, Test Circuit 4	+25°C		6		pC
Off Isolation	O _{ISO}	R _L = 50Ω, f = 1MHz, Test Circuit 5	+25°C		-83		dB
Input Off-Capacitance	C _{X-(OFF)}	V _{X-} = 0V, f = 1MHz, Test Circuit 6	+25°C		4.7		pF
Output Off-Capacitance	C _{X(OFF)}	V _{X-} = 0V, f = 1MHz, Test Circuit 6	+25°C		12.7		pF
Output On-Capacitance	C _{X(ON)}	V _{X-} = 0V, f = 1MHz, Test Circuit 6	+25°C		16		pF
-3dB Bandwidth	BW	R _L = 50Ω	+25°C		180		MHz
Total Harmonic Distortion	THD	R _L = 600Ω, 5V _{P-P} , f = 20Hz to 20kHz	+25°C		0.7		%
POWER SUPPLY							
Power Supply Range	V _{CC}		Full	2.5		5.5	V
Power Supply Current	I _{CC}	V _{CC} = 5.0V, V _A , V _B , V _C , V _{ENABLE} = V _{CC} or 0	+25°C		0.001	6	μA

ELECTRICAL CHARACTERISTICS (continued)(V_{CC} = 3.3V, Full = -40°C to +85°C, typical values are at T_A = +25°C, unless otherwise noted.)

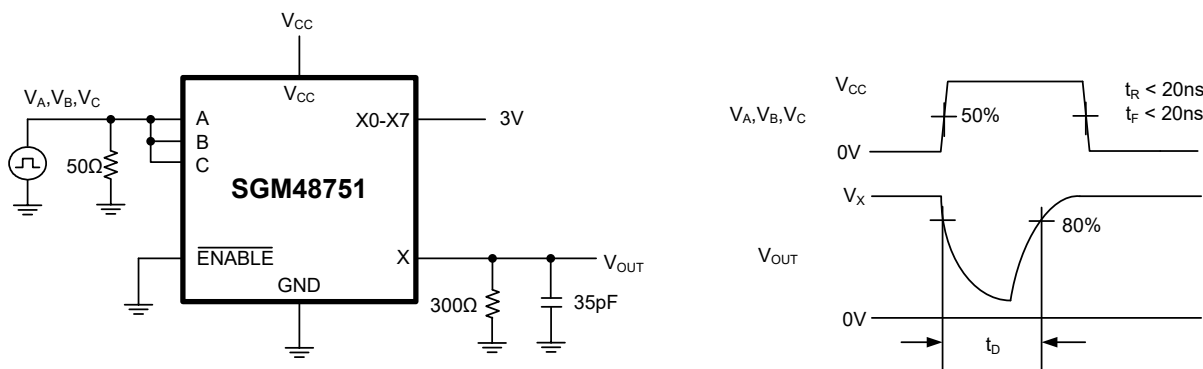
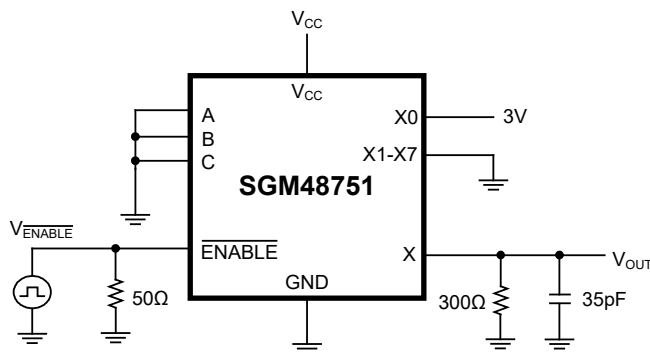
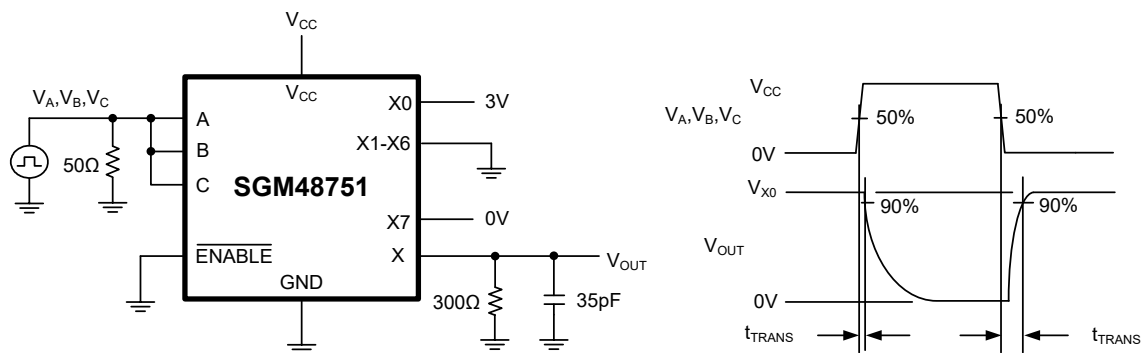
PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{X-} , V _X		Full	GND		V _{CC}	V
On-Resistance	R _{ON}	I _X = 1mA	+25°C		80	110	Ω
			Full			116	
X ₋ Off Leakage Current	I _{X-(OFF)}	V _{X-} = 1V, 3V, V _X = 3V, 1V	+25°C		1	1000	nA
X Off Leakage Current	I _{X(OFF)}	V _{X-} = 1V, 3V, V _X = 3V, 1V	+25°C		1	1000	nA
X On Leakage Current	I _{X(ON)}	V _X = 3V, 1V	+25°C		1	1000	nA
DIGITAL I/O							
Logic Input Logic Threshold High	V _{AH} , V _{BH} , V _{CH} , V _{ENABLE}		+25°C	1.7			V
Logic Input Logic Threshold Low	V _{AL} , V _{BL} , V _{CL} , V _{ENABLE}		+25°C			0.5	V
Input-Current High	I _{AH} , I _{BH} , I _{CH} , I _{ENABLE}	V _A , V _B , V _C , V _{ENABLE} = V _{CC}	+25°C		1	1000	nA
Input-Current Low	I _{AL} , I _{BL} , I _{CL} , I _{ENABLE}	V _A , V _B , V _C , V _{ENABLE} = 0V	+25°C		1	1000	nA
DYNAMIC CHARACTERISTICS							
Address Transition Time	t _{TRANS}	V _{X-} = 3V/0V, R _L = 300Ω, C _L = 35pF, Test Circuit 1	+25°C		150		ns
ENABLE Turn-On Time	t _{ON}	V _{X-} = 3V, R _L = 300Ω, C _L = 35pF, Test Circuit 2	+25°C		110		ns
ENABLE Turn-Off Time	t _{OFF}	V _{X-} = 3V, R _L = 300Ω, C _L = 35pF, Test Circuit 2	+25°C		100		ns
Internal A, B, C Rise Time	t _R		+25°C		80		ns
Internal A, B, C Fall Time	t _F		+25°C		85		ns
Break-Before-Make Time Delay	t _D	V _{X-} = 3V, R _L = 300Ω, C _L = 35pF, Test Circuit 3	+25°C		80		ns
-3dB Bandwidth	BW	R _L = 50Ω	+25°C		180		MHz
Charge Injection	Q	R _S = 0Ω, C = 1nF, V _S = 2.5V, Test Circuit 4	+25°C		4		pC
POWER SUPPLY							
Power Supply Current	I _{CC}	V _A , V _B , V _C , V _{ENABLE} = V _{CC} or 0	+25°C		0.001	3	μA

TYPICAL PERFORMANCE CHARACTERISTICS

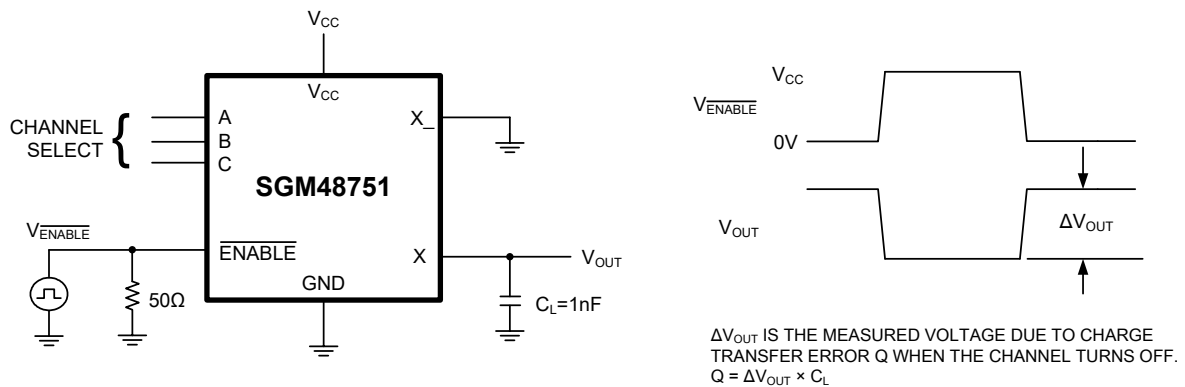
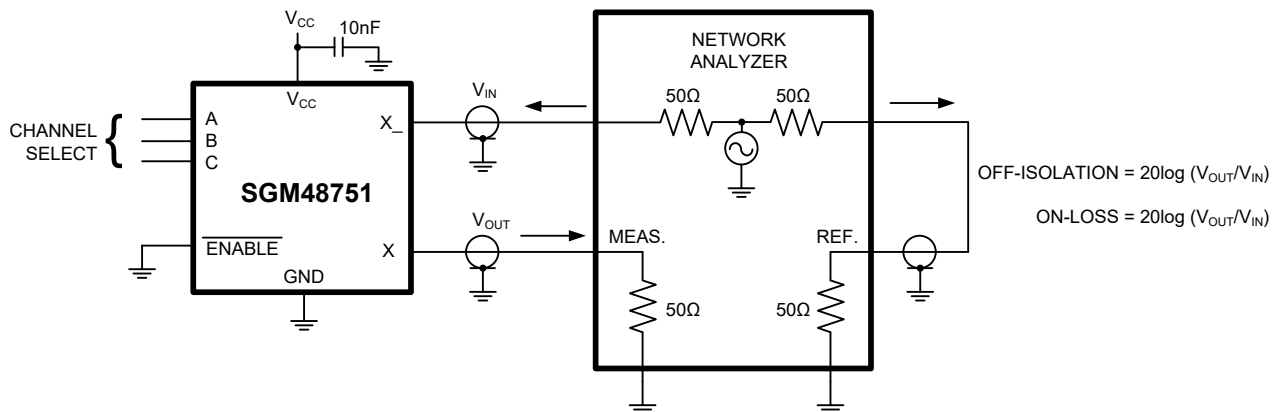
V_{CC} = 5.0V, unless otherwise noted.



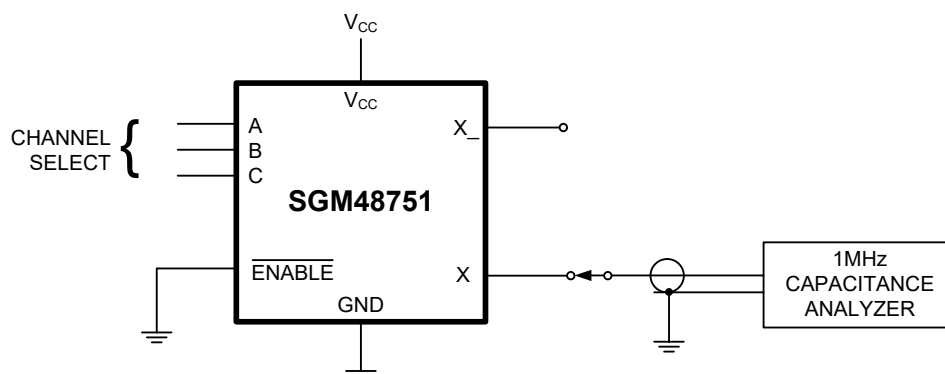
TEST CIRCUITS



TEST CIRCUITS (continued)

Test Circuit 4. Charge Injection (Q)

Test Circuit 5. Off Isolation, On Loss



Test Circuit 6. Capacitance

APPLICATION INFORMATION

Power-Supply Considerations

Overview

The SGM48751 construction is typical of most CMOS analog switch. It supports single power supply. V_{CC} and GND are used to drive the internal CMOS switches and set the limits of the analog voltage on any switch. Reverse ESD protection diodes are internally connected between each analog-signal pin and both V_{CC} and GND. If any analog signal exceeds V_{CC} or GND, one of these diodes will conduct. During normal operation, these and other reverse-biased ESD diodes leak, forming the only current drawn from V_{CC} or GND.

Virtually all the analog leakage current comes from the ESD diodes. Although the ESD diodes on a given signal pin are identical and therefore fairly well balanced, they are reverse biased differently. Each is biased by either V_{CC} or GND and the analog signal. This means their leakages will vary as the signal varies. The difference in the two diode leakages to the V_{CC} and GND pins constitutes the analog-signal-path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. This is why both sides of a given switch can show leakage currents of either the same or opposite polarity.

Over-Voltage Protection

Proper power-supply sequencing is recommended for the CMOS device. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V_{CC} on first, followed by the logic inputs and analog signals. If power-supply sequencing is not possible, add one 100 Ω resistor in series with the supply V_{CC} pin for over-voltage protection (Figure 1).

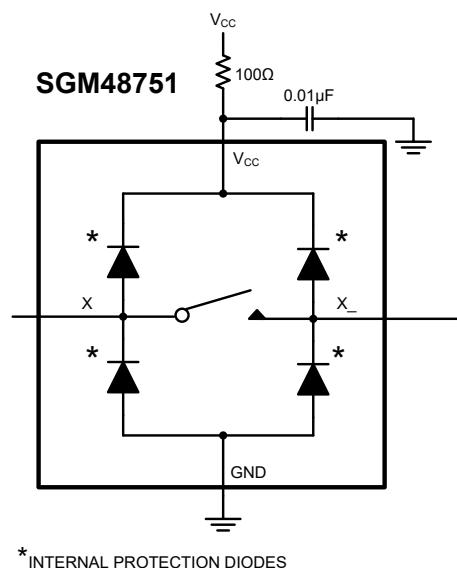


Figure 1. Over-Voltage Protection Using External Resistor

REVISION HISTORY

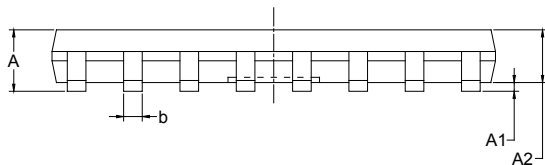
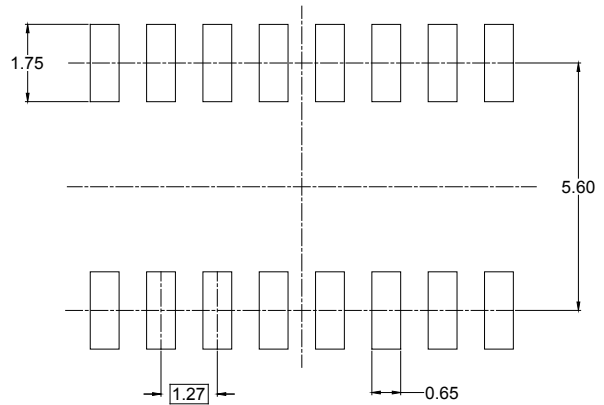
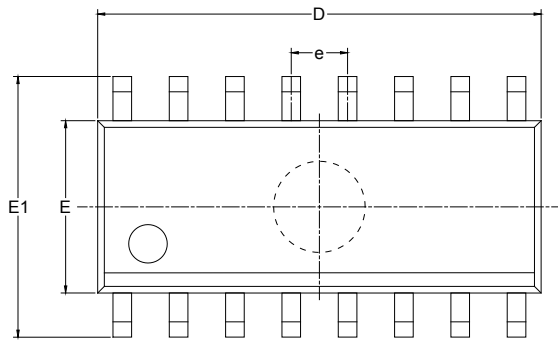
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

APRIL 2019 – REV.A.1 to REV.A.2		Page
Updated Absolute Maximum Ratings section.....		2
NOVEMBER 2014 – REV.A to REV.A.1		Page
Updated Electrical Characteristics section.....		4, 5
Changes from Original (SEPTEMBER 2014) to REV.A		Page
Changed from product preview to production data.....		All

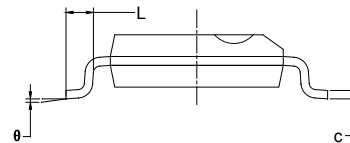
PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

SOIC-16



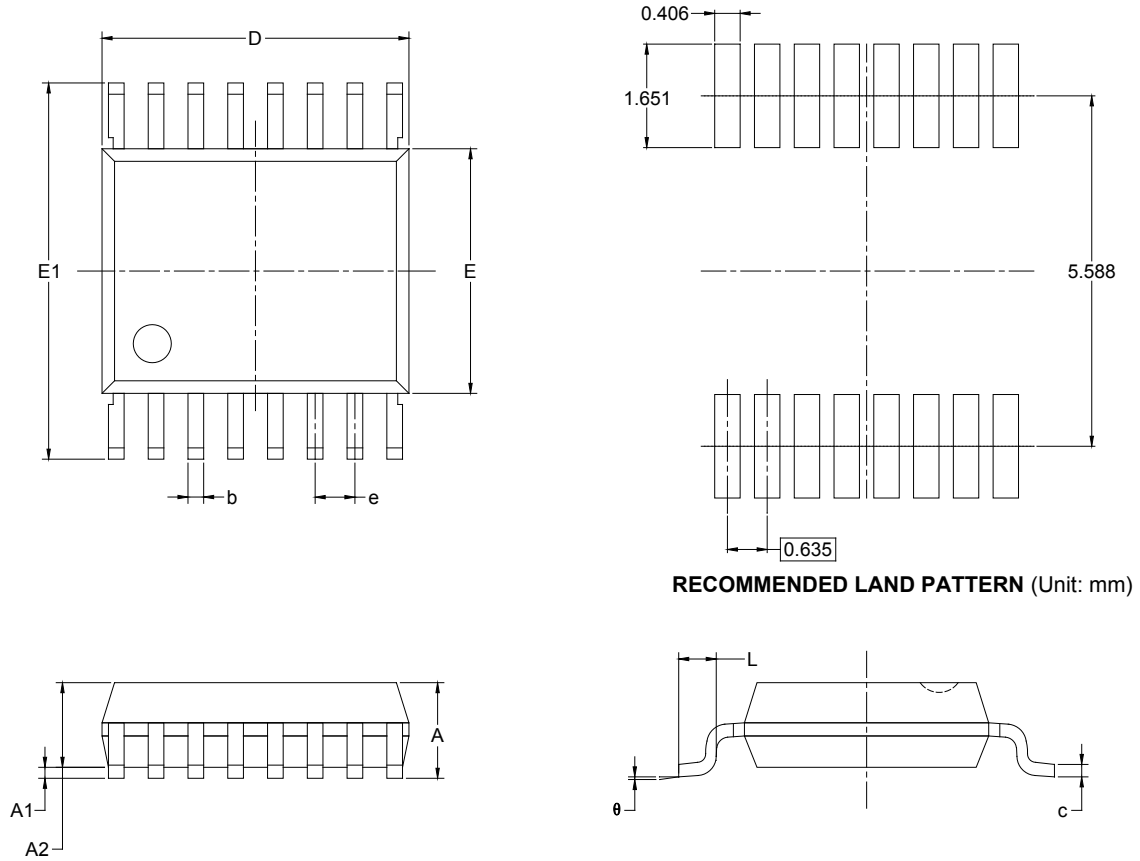
RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	9.800	10.200	0.386	0.402
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27 BSC		0.050 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

PACKAGE OUTLINE DIMENSIONS

SSOP-16

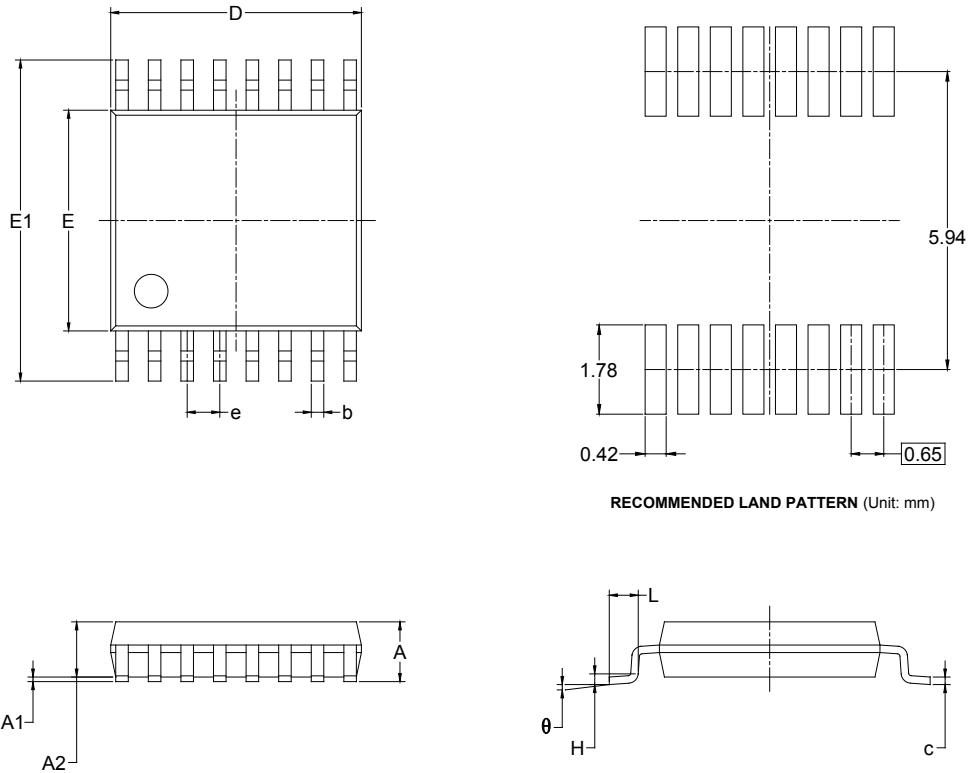


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.200	0.300	0.008	0.012
c	0.170	0.250	0.007	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	0.635 BSC		0.025 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

TSSOP-16

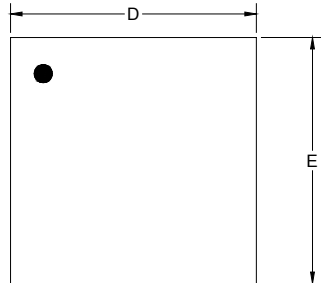


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D	4.860	5.100	0.191	0.201
E	4.300	4.500	0.169	0.177
E1	6.200	6.600	0.244	0.260
e	0.650 BSC		0.026 BSC	
L	0.500	0.700	0.02	0.028
H	0.25 TYP		0.01 TYP	
θ	1°	7°	1°	7°

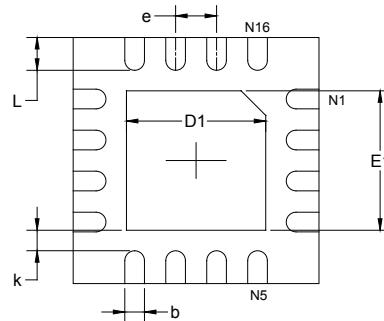
PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

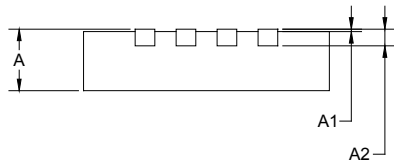
TQFN-3×3-16L



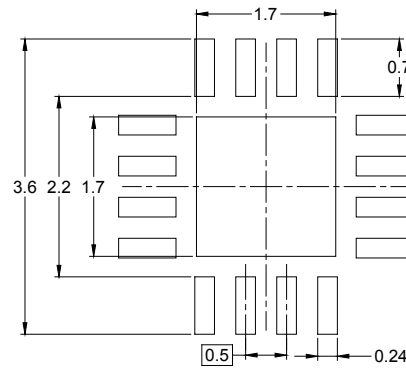
TOP VIEW



BOTTOM VIEW



SIDE VIEW



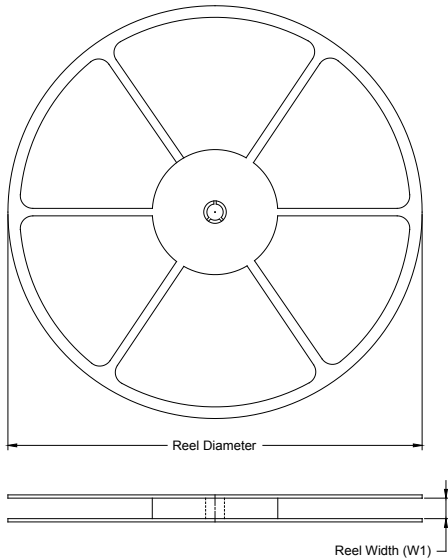
RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A2	0.203 REF		0.008 REF	
D	2.900	3.100	0.114	0.122
D1	1.600	1.800	0.063	0.071
E	2.900	3.100	0.114	0.122
E1	1.600	1.800	0.063	0.071
k	0.200 MIN		0.008 MIN	
b	0.180	0.300	0.007	0.012
e	0.500 TYP		0.020 TYP	
L	0.300	0.500	0.012	0.020

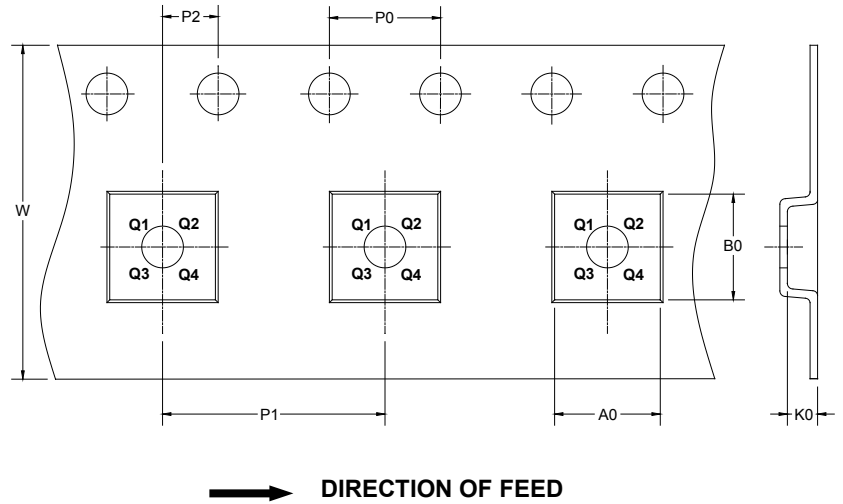
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

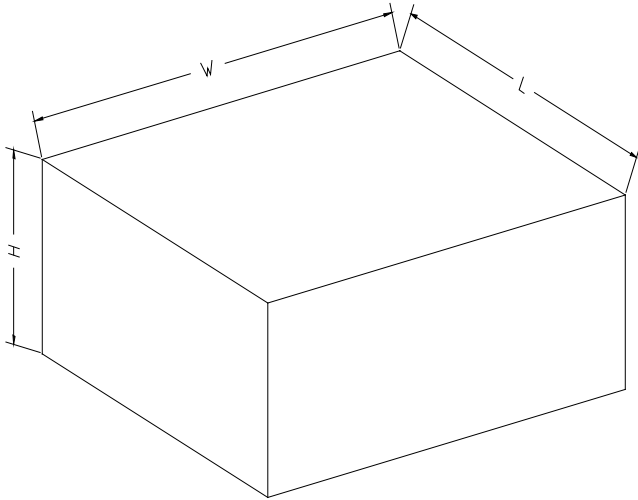
KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC-16	13"	16.4	6.50	10.30	2.10	4.0	8.0	2.0	16.0	Q1
SSOP-16	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
TSSOP-16	13"	12.4	6.90	5.60	1.20	4.0	8.0	2.0	12.0	Q1
TQFN-3×3-16L	13"	12.4	3.35	3.35	1.13	4.0	8.0	2.0	12.0	Q1

DD0001

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13"	386	280	370	5

DD0002